



MMBD4448HT /HTA /HTC /HTS

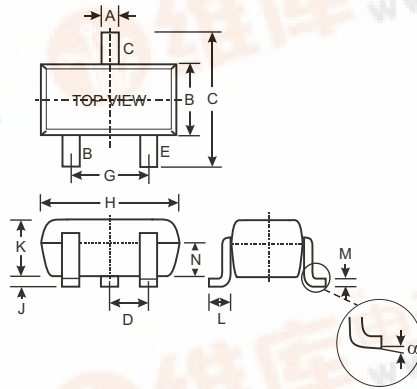
SURFACE MOUNT FAST SWITCHING DIODE

Features

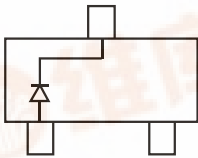
Ultra-Small Surface Mount Package
Fast Switching Speed
For General Purpose Switching Applications
High Conductance

Mechanical Data

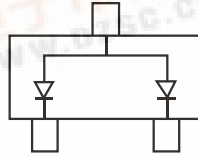
Case: SOT-523, Molded Plastic
Case Material - UL Flammability Rating
Classification 94V-0
Moisture sensitivity: Level 1 per J-STD-020A
Terminals: Solderable per MIL-STD-202, Method 208
Polarity: See Diagrams Below
Marking: See Diagrams Below & Page 2



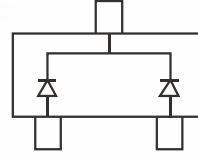
SOT-523			
Dim	Min	Max	Typ
A	0.15	0.30	0.22
B	0.75	0.85	0.80
C	1.45	1.75	1.60
D			0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
J	0.00	0.10	0.05
K	0.60	0.80	0.75
L	0.10	0.30	0.22
M	0.10	0.20	0.12
N	0.45	0.65	0.50
	0	8	
All Dimensions in mm			



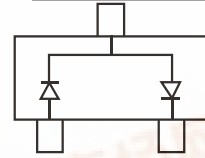
MMBD4448HT Marking: A3



MMBD4448HTA Marking: A6



MMBD4448HTC Marking: A7



MMBD4448HTS Marking: AB

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	80	V
RMS Reverse Voltage	$V_{R(RMS)}$	57	V
Forward Continuous Current (Note 1)	I_{FM}	500	mA
Average Rectified Output Current (Note 1)	I_O	250	mA
Non-Repetitive Peak Forward Surge Current @ $t = 1.0\text{ s}$ @ $t = 1.0\text{ s}$	I_{FSM}	4.0 2.0	A
Power Dissipation (Note 1)	P_d	150	mW
Thermal Resistance Junction to Ambient (Note 1)	R_{JA}	833	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	80		V	$I_R = 2.5\text{ A}$
Forward Voltage (Note 2)	V_F	0.62	0.72 0.855 1.0 1.25	V	$I_F = 5.0\text{mA}$ $I_F = 10\text{mA}$ $I_F = 100\text{mA}$ $I_F = 150\text{mA}$
Leakage Current (Note 2)	I_R		100 50 30 25	nA A A nA	$V_R = 70\text{V}$ $V_R = 75\text{V}, T_j = 150^\circ\text{C}$ $V_R = 25\text{V}, T_j = 150^\circ\text{C}$ $V_R = 20\text{V}$
Total Capacitance	C_T		3.5	pF	$V_R = 6\text{V}, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}		4.0	ns	$V_R = 6\text{V}, I_F = 5\text{mA}$

Notes: 1. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

2. Short duration test pulse used to minimize self-heating effect.

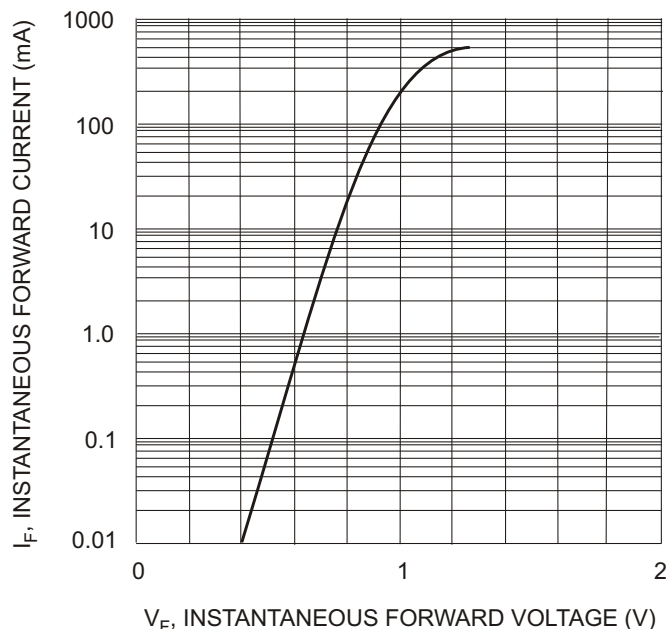


Fig. 1 Forward Characteristics

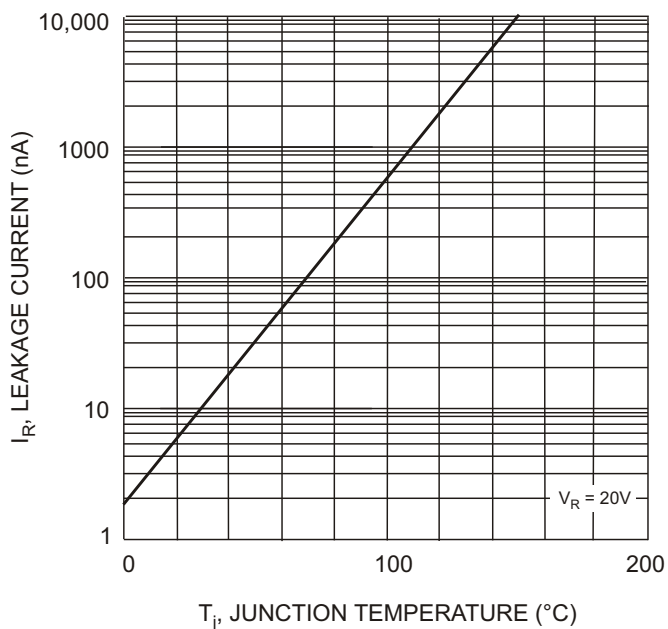
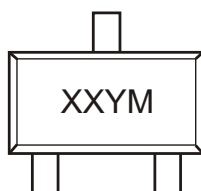


Fig. 2 Leakage Current vs Junction Temperature

Ordering Information (Note 3)

Device	Packaging	Shipping
MMBD4448HT-7	SOT-523	3000/Tape & Reel
MMBD4448HTA-7	SOT-523	3000/Tape & Reel
MMBD4448HTC-7	SOT-523	3000/Tape & Reel
MMBD4448HTS-7	SOT-523	3000/Tape & Reel

Marking Information



XX = Product Type Marking Code (See Page 1 Diagrams)
 YM = Date Code Marking
 Y = Year (ex: N = 2002)
 M = Month (ex: 9 = September)

Date Code Key

Year	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	M	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Notes: 3. For Packaging Details: go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.